

# International IOR Rectifier

SCHOTTKY RECTIFIER  
HIGH EFFICIENCY SERIES

PD -20353D

## 22GQ100

30A, 100V

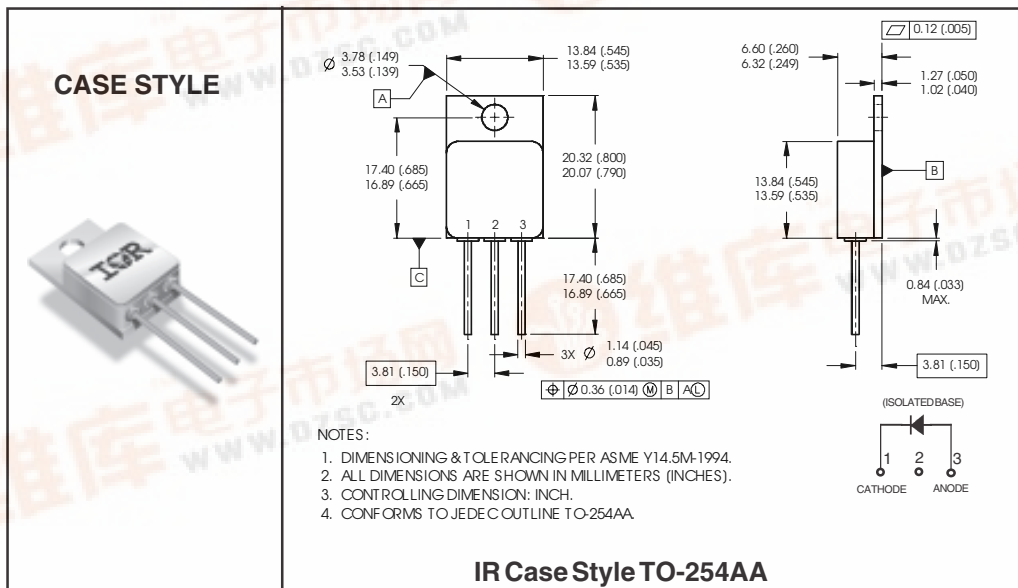
### Major Ratings and Characteristics

Characteristics	22GQ100	Units
$I_{F(AV)}$ Rectangular waveform	30	A
$V_{RRM}$	100	V
$I_{FSM}$ @ $t_p = 8.3ms$ half-sine	400	A
$V_F$ @ $30A_{pk}$ , $T_J = 125^\circ C$	0.90	V
$T_J$ , $T_{stg}$ Operating and storage	-55 to 150	$^\circ C$

### Description/Features

The 22GQ100 Schottky rectifier has been expressly designed to meet the rigorous requirements of hi-rel environments. It is packaged in the hermetic isolated TO-254AA package. The device's forward voltage drop and reverse leakage current are optimized for the lowest power loss and the highest circuit efficiency for typical high frequency switching power supplies and resonant power converters. Full MIL-PRF-19500 quality conformance testing is available on source controlled drawings to TX, TXV and S levels.

- Hermetically Sealed
- High Frequency Operation
- Guard Ring for Enhanced Ruggedness and Long Term Reliability
- Schottky Diodes Connected in Series
- Electrically Isolated



**Voltage Ratings**

Part number	22GQ100
V <sub>R</sub> Max. DC Reverse Voltage (V)	100
V <sub>RWM</sub> Max. Working Peak Reverse Voltage (V)	

**Absolute Maximum Ratings**

Parameters	Limits	Units	Conditions
I <sub>F(AV)</sub> Max. Average Forward Current See Fig. 5	30	A	50% duty cycle @ T <sub>C</sub> = 100°C, rectangular waveform
I <sub>FSM</sub> Max. Peak One Cycle Non - Repetitive Surge Current	400	A	@ t <sub>p</sub> = 8.3 ms half-sine

**Electrical Specifications**

Parameters	Limits	Units	Conditions	
V <sub>FM</sub> Max. Forward Voltage Drop See Fig. 1 ①	1.1	V	@ 20A	T <sub>J</sub> = 25°C
	1.6	V	@ 35A	
	0.9	V	@ 20A	T <sub>J</sub> = 125°C
	1.3	V	@ 35A	
I <sub>RM</sub> Max. Reverse Leakage Current See Fig. 2 ①	0.8	mA	T <sub>J</sub> = 25°C	V <sub>R</sub> = rated V <sub>R</sub>
	45	mA	T <sub>J</sub> = 125°C	
C <sub>T</sub> Max. Junction Capacitance	1400	pF	V <sub>R</sub> = 5V <sub>DC</sub> ( 1MHz, 25°C)	
L <sub>S</sub> Typical Series Inductance	7.8	nH	Measured from anode lead to cathode lead 6mm ( 0.025 in.) from package	

**Thermal-Mechanical Specifications**

Parameters	Limits	Units	Conditions	
T <sub>J</sub> Max. Junction Temperature Range	-55 to 150	°C		
T <sub>stg</sub> Max. Storage Temperature Range	-55 to 150	°C		
R <sub>thJC</sub> Max. Thermal Resistance, Junction to Case	1.0	°C/W	DC operation	See Fig. 4
wt Weight (Typical)	9.3	g		
Die Size	200X200	mils		
Case Style	TO-254AA			

① Pulse Width &lt; 300μs, Duty Cycle &lt; 2%

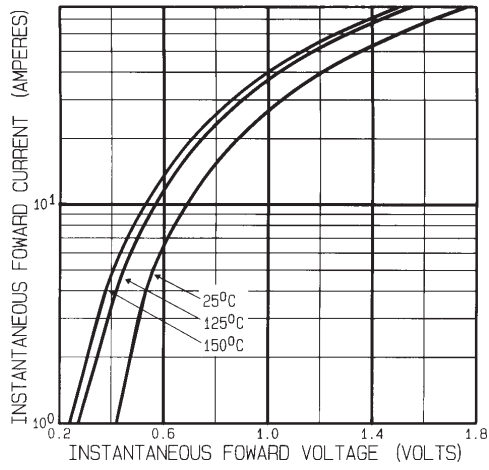


Fig. 1 - Max. Forward Voltage Drop Characteristics

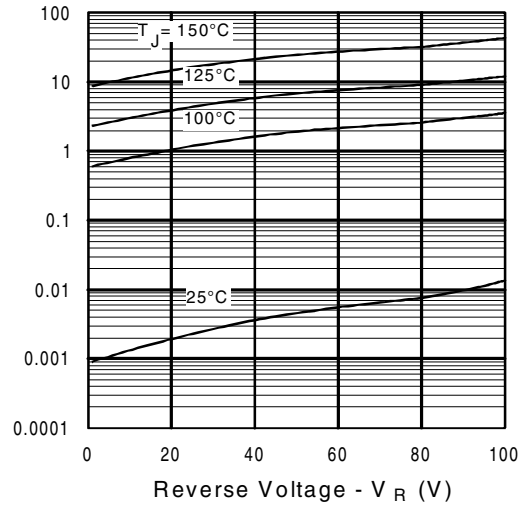


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

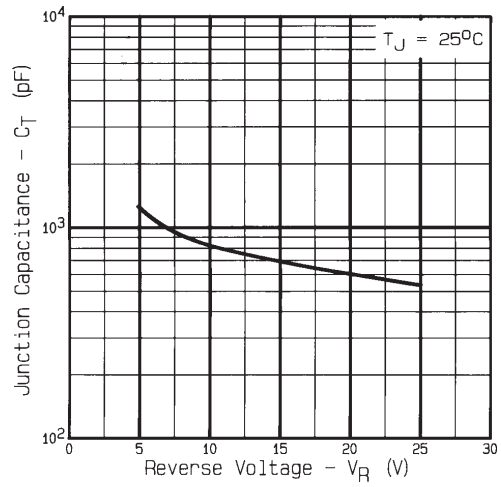


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

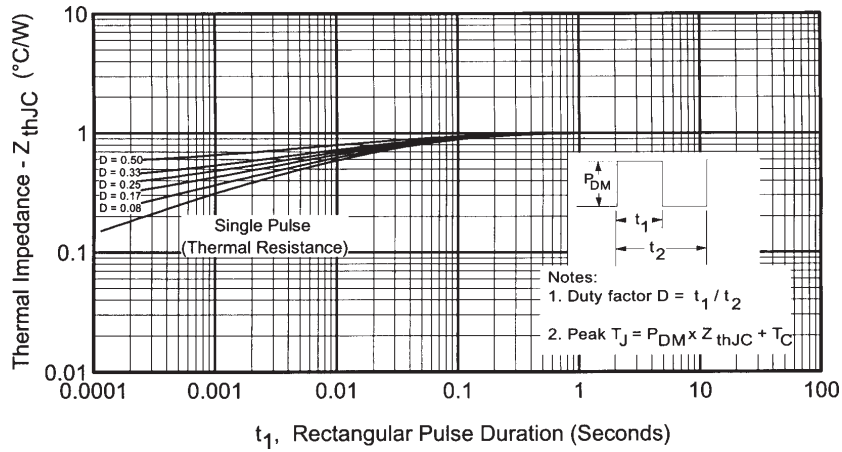


Fig. 4 - Max. Thermal Impedance  $Z_{thJC}$  Characteristics

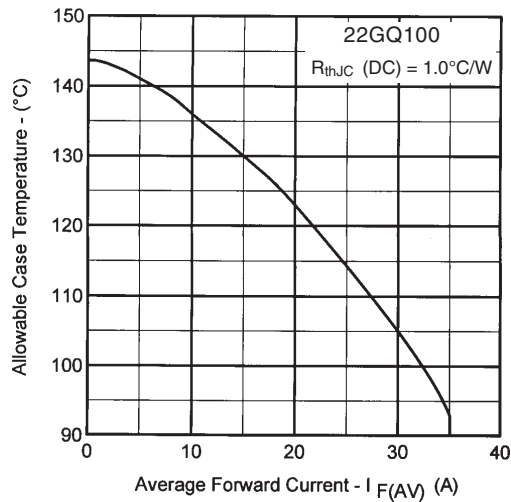


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current